

L Number	Hits	Search Text	DB	Time stamp
1	244	vacuum near microelectronic and electron adj emitter	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/10 07:32
2	49	vacuum adj microelectronic near device and electron near emitter and substrate and electric near field	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/10 07:39
3	4	("5773921"   "5855675"   "5892231"   "6512235").PN.	USPAT	2004/05/10 07:36
4	3	("5089742"   "5138220"   "5495143").PN.	USPAT	2004/05/10 07:37
5	6	vacuum adj microelectronic and electron near emitter and applying adj electric near field	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/10 07:46
6	8	("4041346"   "4272699"   "4301369"   "5395774"   "5583393"   "5726524"   "5773921"   "5872422").PN.	USPAT	2004/05/10 07:42
7	10102	vacuum adj microelectronic near device and electron near emitter and 29/\$.ccls.applying adj electric near field	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/10 07:50
8	9	vacuum adj microelectronic near device and electron near emitter and 29/\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/10 07:48
9	0	microelectronic near device and electron near emitter and applying adj electric near field and 250/\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/10 07:51
10	3	microelectronic near device and electron near emitter and applying adj electric near field and 313/\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/10 07:52
11	0	microelectronic near device and electron near emitter and applying adj electric near field and 437/\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/10 07:52

12	112	microelectronic near device and electron near emitter and electric near field	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/10 07:53
13	62	microelectronic near device and electron near emitter and electric near field and 313/\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/10 07:53
14	31	microelectronic near device and electron near emitter and electric near field and 445/\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/10 07:55
15	80	microelectronic near device and electron near emitter and electric near field and (445/51; 445/50 ; 445/24 ; 445/49 ; 313/495 ; 313/496 ; 313/497 ; 313/306 ; 313/307 ; 313/308 ; 313/309 ; 313/310 ; 313/311).ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/10 07:56
16	0	microelectronic near device and electron near emitter and electric near field and 29/\$.ccls. and 313/\$.ccls. and 445/\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/10 07:57
17	8	microelectronic near device and electron near emitter and electric near field and 313/\$.ccls. and 445/\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2004/05/10 07:57
20	4	("5773921"   "5855675"   "5892231"   "6512235").PN.	USPAT	2004/05/10 07:59